In-plane anisotropy on the transport properties in the modulated Bi$_2$O$_2$-based conductors Bi-2212 and Bi-Sr-Co-O

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We investigated the in-plane anisotropy on the resistivity and thermopower of the Bi$_2$Sr$_2$CaCu$_2$O$_8$+δ (Bi-2212) and Bi-Sr-Co-O (BiCo) single crystals. In Bi-2212, the $b$-axis resistivity is higher than the $a$-axis resistivity, and is expressed as a sum of the $a$-axis resistivity and an additional residual resistivity. A downward deviation due to pseudogap is observed below a characteristic temperature $T^*$, which is isotropic in the form of conductivity. These results suggest that the modulation structure along the $b$-axis works as an anisotropic scattering center, but does not affect the pseudogap formation. On the other hand, the anisotropy of the resistivity and the thermopower in Pb-doped BiCo is substantial, probably owing to the misfit structure between the hexagonal CoO$_2$ layer and the rock salt BiO$_2$ layer. However, the anisotropy in the resistivity in Pb-free BiCo is very small, suggesting that the in-plane anisotropy is averaged by the modulation structure, whose direction is tilted by 45° from the $a$- and $b$-axes.

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I. INTRODUCTION

Bi$_2$Sr$_2$CaCu$_2$O$_8$+δ (Bi-2212) and Bi$_2$Sr$_2$Co$_2$O$_x$ (BiCo) commonly have a Bi$_2$O$_2$ block layer, in which the lattice is modulated by the excess oxygen. Although these two materials have a similar crystal structure of alternating stacks of the Bi$_2$O$_2$ layer and the CuO$_2$ / CoO$_2$ layer, they show quite different physical properties; Bi-2212 is known as a high-temperature superconductor, while BiCo is known as a thermoelectric material [1]. High resolution transmission electron microscope studies of the Bi-based superconductors (including Bi-2212) have clarified that they have strongly modulated structure along $b$-axis and that modulation periodicity is reported about 4.8b for Pb-free Bi-2212 [2]. This modulated structure disappears in Pb-doped Bi-2212 [3]. BiCo was first thought as having a structure isomorphic to that of Bi-2212. However, it turned out to have a misfit layer structure along the $b$ axis, which consists of alternating stacks of the rock-salt Bi$_2$O$_2$ layers and the hexagonal CoO$_2$ layers [4]. The modulation structure also exists in the pure BiCo although its direction is tilted by 45° from $a$- and $b$-axes in contrast with Bi-2212. Since the CuO$_2$ and CoO$_2$ layers are responsible for electric conduction, it is interesting how the electric properties are affected by the modulation properties and the misfit structure. Here, we report on the in-plane anisotropy on the resistivity and thermopower of the two compounds.

II. EXPERIMENTAL

Superconducting compound Bi-2212 with Bi:Sr=2.2:1.8 and thermoelectric material Pb-free and 20% Pb-doped BiCo (Bi$_{1.6}$Pb$_{0.4}$Sr$_2$Co$_2$O$_x$) were used in this study. Single crystals of Bi-2212 and BiCo were grown by a traveling solvent floating zone method. Starting composition of Bi-2212 and BiCo was Bi$_2$Sr$_{1.8}$CaCu$_2$O$_8$+δ and (Bi,Pb)$_2$Sr$_2$Co$_2$O$_x$ respectively. The growth velocity was adopted to be 0.5mm/h, and the growth atmosphere was a mixed gas flow of O$_2$ (20%) and Ar (80%). Structural analysis for BiCo was performed by using 4-axis X-ray diffractometer (MAC Science MXC) and transmission electron microscope (JEOL JEM-100CX). Pb-doped BiCo was found to monoclinic symmetry with lattice parameter of $a$=4.91Å, $b$=5.22Å, $c$=29.98Å, $\alpha$ and $\gamma$ $\approx$90°, $\beta$ $\approx$92°. In TEM diffraction patterns, we clearly observed a rock-salt diffraction pattern from the BiO layer and a hexagonal diffraction pattern from the CoO$_2$ layer as was previously reported in ref. [4]. The Montgomery method was adopted to measure the in-plane resistivity of Bi-2212 because they show rather small anisotropy between the $a$- and $b$-axes. On the other hand, the resistivity of BiCo was measured using a standard four probe method, where the current contacts were carefully mounted on the side surface (ac- or bc-surface) so that current density should be homogeneous everywhere in the sample. The thermopower was measured using a

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FIG. 1: $a$-axis resistivity $\rho_a$ and $b$-axis resistivity $\rho_b$ of Bi$_2$Sr$_{1.8}$CaCu$_2$O$_{8+\delta}$ single crystal for various doping levels measured by the Montgomery method.

FIG. 2: (a): The deviation from $T$-linear extrapolation ($\Delta \rho_a$ and $\Delta \rho_b$). (b): The change in conductivity $\Delta \sigma = \Delta \rho / \rho^2$.

III. RESULTS AND DISCUSSION

A. Anisotropy in Bi-2212

Figure 1 shows the temperature dependence of the $a$- and $b$-axis resistivities ($\rho_a$ and $\rho_b$) for various doping levels. The magnitudes and the slopes $d\rho / dT$ monotonically decrease with increasing oxygen contents $\delta$, indicating that the carriers are actually doped with increasing $\delta$. $\rho_b$ is higher than $\rho_a$, where $\rho_b$ is roughly expressed as a sum of $\rho_a$ and a $T$-independent residual resistivity ($\rho_0$) at high temperature. An underdoped sample shows a typical downward deviation from high temperature $T$-linear behavior below a characteristic temperature $T^*$, which implies pseudogap formation. In Fig. 2(a), we show the magnitudes of the deviation from $T$-linear extrapolation ($\Delta \rho_a$ and $\Delta \rho_b$) for oxygen content $\delta \sim 0.23$, and 0.25. As seen in Fig. 2(a), $\Delta \rho_a$ and $\Delta \rho_b$ deviate each other below the pseudogap temperature $T^*$, indicating that the decrease of $\rho_b$ is more rapid than that of $\rho_a$. Although $\Delta \rho_a$ and $\Delta \rho_b$ are anisotropic in the form of resistivity, there is no in-plane anisotropy in the deviation in conductivity ($\Delta \sigma = \Delta \rho / \rho^2$) as seen in Fig. 2(b).

Figure 3 shows the temperature dependence of the thermopower in various doping levels measured along the $a$- and $b$-axes. The magnitude of the thermopower decreases with increasing $\delta$, also indicating that the excess oxygen causes the carrier doping. Typical negative slope at high temperature was observed in all the doping levels. In contrast with the in-plane resistivities, there is no anisotropy in the thermopower within our experimental error of 10%.

These results suggest that the modulation structure along the $b$-axis works as an anisotropic scattering center above $T^*$, but does not affect the pseudogap value. In principle, thermopower does not attribute to the scattering rate. In YBa$_2$Cu$_3$O$_7$ (YBCO) case, since the CuO chain also attributes to the electron conduction, there exists large anisotropy in the normal-state resistivity. In superconducting state, angle-resolved photoemission spectroscopy (ARPES) measurement reported a significant (~50%) difference in the gap magnitude between $X$ and...
FIG. 4: $a$-axis resistivity $\rho_a$ and $b$-axis resistivity $\rho_b$ of (Bi,Pb)-Sr-Co-O single crystal measured by the four-probe method.

Y point $^3$. However, this kind of gap anisotropy has not been reported in ARPES measurement for Bi-2212. In the superconducting state in the Bi-2212, optical conductivity shows an upturn behavior at low frequencies for the $b$-axis polarization that is not present in the $a$-axis polarization $^6$. This upturn behavior is very similarly seen in the optical conductivity of Zn doped YBCO $^8$. This indicates the presence of low-lying excitations along the $b$-axis, perhaps due to an additional scattering caused by the modulation structure. Thus, an anisotropy in the scattering rate exists not only in the normal state but also in the superconducting state.

B. Anisotropy in BiCo

Figure 4 shows the temperature dependence of the resistivities for the $a$- and $b$-axis directions. Pb-doped BiCo exhibits lower resistivities than Pb-free BiCo, suggesting that carrier is doped through the substitution of divalent Pb$^{2+}$ for trivalent Bi$^{3+}$. As for the Pb-free sample, $\rho_a$ and $\rho_b$ exhibit metallic behavior near room temperature and insulating behavior below 50K and the in-plane anisotropy is relatively small. On the other hand, the Pb-doped sample shows a significant anisotropy at low temperature; $\rho_a$ remains metallic down to 4.2K, whereas $\rho_b$ shows an upturn near 50K.

Figure 5 shows the temperature dependence of the $a$- and $b$-axis thermopower for the Pb-free and Pb-doped samples. In contrast with Bi-2212, they exhibit a large anisotropy, where the $b$-axis thermopower is about two times larger than the $a$-axis thermopower around 50K. At room temperature, the $a$-axis thermopower is larger than the $b$-axis thermopower by about 10µV/K. Temperature independent thermopower at high temperature is often explained in terms of an entropy per site (the Heikes formula) $^9$, which is in principal isotropic. Thus the Heikes formula is unlikely to be applicable to the thermopower of BiCo. The large anisotropy in the Pb-doped sample would come from the misfit structure along the $b$-axis. On the other hand, in the case of the resistivities of the Pb-free sample, anisotropy would be averaged by the modulation structure, whose direction is tilted by 45° from the $a$- and $b$-axes. It was pointed out that the physical properties of the layered cobalt oxides resemble those of the Ce-based compounds $^{11}$. The thermopower of CeCu$_2$Ge$_2$ increases with increasing pressure. In the Ce-based compound, pressure shrinks the lattice to increase the hybridization between the Ce 4f state and the conduction band. The large thermopower of BiCo would be also attributed to the increase of hybridization, which comes from chemical pressure due to the misfit structure.

IV. CONCLUSION

In conclusion, we investigated the in-plane anisotropy on the resistivity and thermopower of the Bi-2212 and Bi-Sr-Co-O. We found in Bi-2212 that the modulation structure causes the residual resistivity on $\rho_b$ as $\rho_b=\rho_a+\rho_0$. However, it does not affect the pseudogap formation and the thermopower. In the case of Pure BiCo, the in-plane anisotropy of the resistivity is averaged by the modulation structure, whose direction is tilted by 45° from the $a$- and $b$-axes. On the other hand, the misfit structure makes the resistivities and thermopowers of BiCo anisotropic. The large anisotropy of BiCo would be attributed to the chemical pressure due to the misfit structure.